

ES1AAS THRU ES1JAS

1A Surface Mount Super Fast Rectifiers

■ Features

- Low profile surface mounted application in order to optimize board space.
- High current capability, low forward voltage drop.
- · High surge capability.
- Superfast recovery time for switching mode application.
- Glass passivated chip junction.
- Suffix "G" indicates Halogen-free part, ex.ES1AASG.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

• Epoxy:UL94-V0 rated flame retardant

· Case: Molded plastic, DO-214AC / SMAS

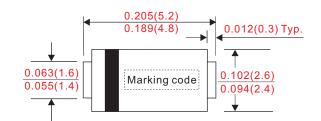
 Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

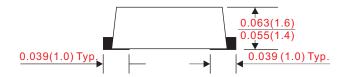
Polarity : Indicated by cathode band

• Weight : Approximated 0.08 gram

Outline

SMAS(DO-214AC)





Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current		Io			1.0	Α
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}			30	А
B	$V_R = V_{RRM} T_A = 25^{\circ}C$				5.0	uA
Reverse current	$V_R = V_{RRM} T_A = 125^{\circ}C$	I _R			100	
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	C,		10		pF
Storage temperature		T _{STG}	-55		+150	°C

Symbol	Marking code	Max. repetitive peak reverse voltage V _{RRM} (V)	Max. RMS voltage V _{RMS} (V)	Max. DC blocking voltage $V_{_{\mathbb{R}}}(V)$	Max. forward voltage $@1A, T_A = 25^{\circ}C$ $V_F(V)$	Max. reverse recovery time(1) T _π (ns)	Operating temperature T _J (°C)
ES1AAS	ES1A	50	35	50			
ES1BAS	ES1B	100	70	100	0.95		
ES1DAS	ES1D	200	140	200		35	-55 ~ +150
ES1GAS	ES1G	400	280	400	1.25		
ES1JAS	ES1J	600	420	600	1.70		

Note : 1. $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$

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■ Rating and characteristic curves

0.8

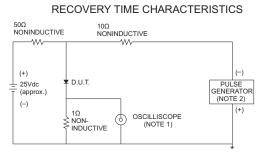
1.0 1.2

FIG.1-TYPICAL FORWARD

FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE

FORWARD VOLTAGE,(V)

1.4



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.

2. Rise Time= 10ns max., Source Impedance= 50 ohms.

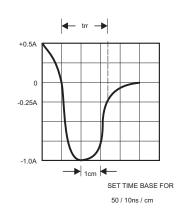


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

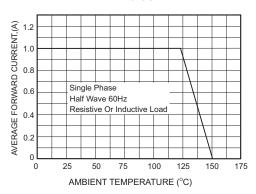


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

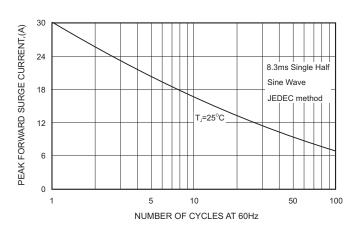
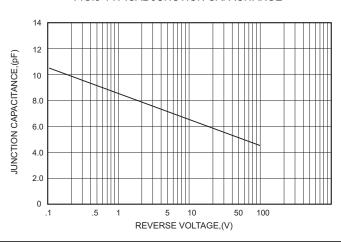


FIG.5-TYPICAL JUNCTION CAPACITANCE



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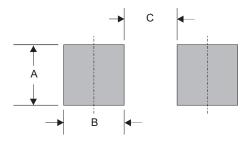
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■ SMAS foot print



Α	В	С		
0.063 (1.60)	0.059 (1.50)	0.110 (2.80)		

Dimensions in inches and (millimeters)

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